NSN 5961-00-421-4763

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-421-4763 **Inclosure Material:** Plastic **Overall Length:** 0.500 inches **Terminal Length:** 0.900 inches **Overall Height:** 0.200 inches **Overall Width:** 0.450 inches **Component Name And Quantity:** 4 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 115.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** Terminal surfaces gold **Precious Material: Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

INO

Fiig:

A110a0